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HMC349ALP4CE



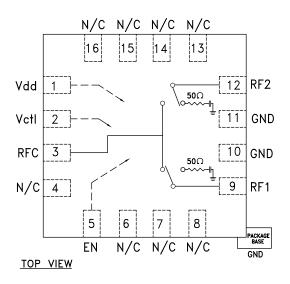
HIGH ISOLATION SPDT Non-Reflective Switch, DC - 4 GHz

Typical Applications

The HMC349ALP4CE is ideal for:

- Basestation Infrastructure
- MMDS & 3.5 GHz WLL
- CATV/CMTS
- Test Instrumentation

Functional Diagram



Features

High Isolation: 67 dB @ 1 GHz

62 dB @ 2 GHz

Single Positive Control: 0/+5V

+53 dBm Input IP3

Non-Reflective Design

All Off State

16 mm² Leadless QFN SMT Package

General Description

The HMC349ALP4CE is a high isolation non-reflective DC to 4 GHz GaAs MESFET SPDT switch in a low cost leadless surface mount package. The switch is ideal for cellular/PCS/3G basestation applications yielding 60 to 65 dB isolation, low 0.9 dB insertion loss and +53 dBm input IP3. Power handling is excellent up through the 3.5 GHz WLL band with the switch offering a P1dB compression point of +31 dBm. Onchip circuitry allows a single positive voltage control of 0/+5 Volts at very low DC currents. An enable input (EN) set to logic high will put the switch in an "all off" state.

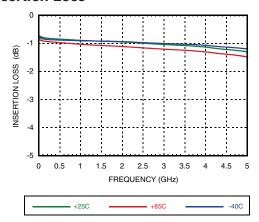
Electrical Specifications, $T_A = +25^{\circ}$ C, Vctl = 0/+5 Vdc, Vdd = +5 Vdc, 50 Ohm System

Parameter	Frequency	Min.	Тур.	Max.	Units
Insertion Loss	DC - 1.0 GHz DC - 2.0 GHz DC - 3.0 GHz DC - 4.0 GHz		0.9 1.0 1.2 1.4	1.2 1.3 1.5 1.7	dB dB dB dB
Isolation (RFC to RF1/RF2)	DC - 1.0 GHz DC - 4.0 GHz	60 55	67 62		dB dB
Return Loss (On State)	DC - 2.0 GHz DC - 3.0 GHz DC - 4.0 GHz		22 20 17		dB dB dB
Return Loss (Off State)	0.5 - 4.0 GHz		20		dB
Input Power for 1 dB Compression	0.25 - 4.0 GHz	30	34		dBm
Input Third Order Intercept (Two-Tone Input Power = +10 dBm Each Tone)	0.25 - 4.0 GHz		53		dBm
Switching Speed	DC - 4.0 GHz				
tRISE, tFALL (10/90% RF) tON, tOFF (50% CTL to 10/90% RF)			60 150		ns ns

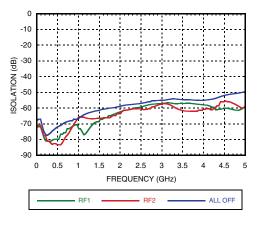




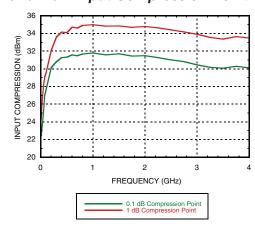
Insertion Loss



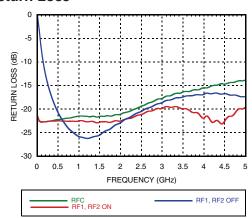
Isolation Between Ports RFC and RF1 / RF2



0.1 and 1 dB Input Compression Point

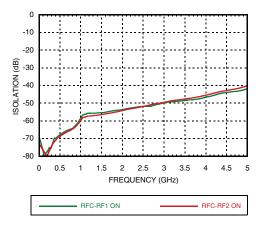


Return Loss

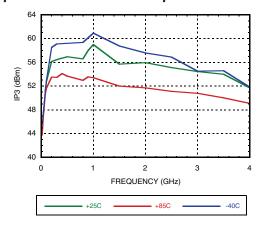


Note: RFC is reflective in "all off" state.

Isolation Between Ports RF1 and RF2



Input Third Order Intercept Point







Absolute Maximum Ratings

	3
RF Input Power (Vdd/Vctl = +5V) (0.25 - 4 GHz) Through Path	+33.6 dBm (T = 85 °C) +28 dBm (T = 125 °C)
	`
Termination Path	+26.5 dBm (T = 85 °C) +21 dBm (T = 125 °C)
Supply Voltage Range (Vdd)	+7 Vdc
Control Voltage Range (Vctl)	-1V to Vdd +1V
Hot Switch Power Level (Vdd = +5V)	+30 dBm (T = 85 °C) +25 dBm (T = 125 °C)
Channel Temperature	150 °C
Continuous Pdiss (T = 85 °C) (derate 14.9 mW/°C for through path, 6.9 mW/°C for termination path above 85 °C)	
Through Path	0.969 W
Termination Path	0.451 W
Thermal Resistance	
Through Path	67.1 °C/W
Termination Path	144.2 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +125 °C
ESD Sensitivity (HBM)	
All pins Vdd to ground	Class 1A 350V

Note: DC blocking capacitors are required at ports RFC, RF1 and RF2. Their value will determine the lowest transmission frequency.

Bias Voltage & Current

Vdd Range = +5.0 Vdc ± 10%		
Vdd (Vdc)	Idd (Typ.) (mA)	ldd (Max.) (mA)
+5.0	1.0	3.5

TTL/CMOS Control Voltages

State	Bias Condition	
Low	0 to +0.8 Vdc @ <1 μA Typical	
High	+2.0 to +5.0 Vdc @ 35 μA Typical	

Truth Table

Control Input Signal Path		ath State	
Vctl	EN	RFC - RF1	RFC - RF2
Low	Low	OFF	ON
High	Low	ON	OFF
Low	High	OFF	OFF
High	High	OFF	OFF







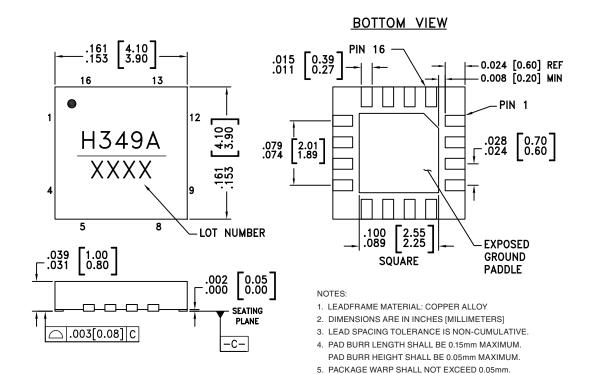
6. ALL GROUND LEADS AND GROUND PADDLE MUST BE

7. REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED

SOLDERED TO PCB RF GROUND.

LAND PATTERN.

Outline Drawing



Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [1]
HMC349ALP4CE	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 [2]	<u>H349A</u> XXXX

^{[1] 4-}Digit lot number XXXX

^[2] Max peak reflow temperature of 260 °C





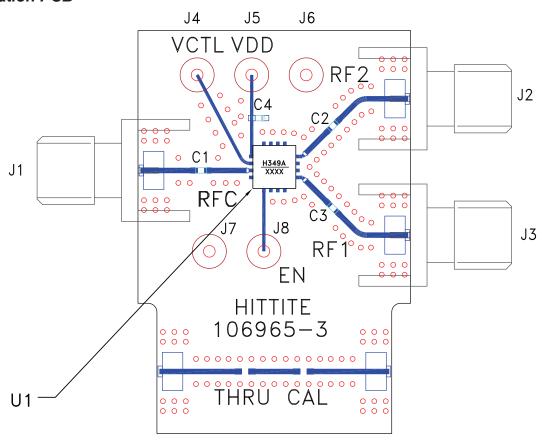
Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1	Vdd	Supply Voltage.	
2	Vctl	Control input. See truth and control voltage tables.	Vetl 134K
3, 9, 12	RFC, RF1, RF2	These pins are DC coupled and matched to 50 Ohms. Blocking capacitors are required.	
4, 6, 7, 8, 13, 14, 15, 16	N/C	No connection. These pins may be connected to RF ground. Performance will not be affected.	
5	EN	Enable. See truth and control voltage tables.	EN 134K
10, 11	GND	Package bottom must also be connected to PCB RF ground.	GND =





Evaluation PCB



List of Materials for Evaluation PCB 106975 - HMC349ALP4C [1]

Item	Description	
J1 - J3	PC Mount SMA RF Connector	
J4 - J8	DC Pin	
C1 - C4	100 pF Capacitor, 0402 Pkg.	
U1	HMC349ALP4CE SPDT Switch	
PCB [2]	106965 Evaluation PCB	

^[1] Reference this number when ordering complete evaluation PCB

The circuit board used in the application should be generated with proper RF circuit design techniques. Signal lines at the RF port should have 50 Ohm impedance and the package ground leads and backside ground slug should be connected directly to the ground plane similar to that shown above. The evaluation circuit board shown above is available from Hittite Microwave Corporation upon request.

^[2] Circuit Board Material: Rogers 4350

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